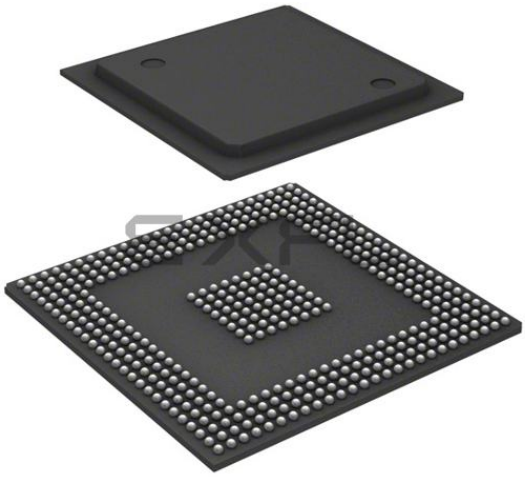

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z7
Core Size	32-Bit Single-Core
Speed	264MHz
Connectivity	CANbus, SCI, SPI
Peripherals	DMA, POR, PWM
Number of I/O	32
Program Memory Size	3MB (3M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	192K x 8
Voltage - Supply (Vcc/Vdd)	1.08V ~ 5.25V
Data Converters	A/D 64x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	416-BBGA
Supplier Device Package	416-PBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5673ff3mvr3

3.3 516-ball TEPBGA Pin Assignments

Figure 11 shows the 516-ball TEPBGA pin assignments in one figure. The same information is shown split into four quadrants in Figure 12 through Figure 15.

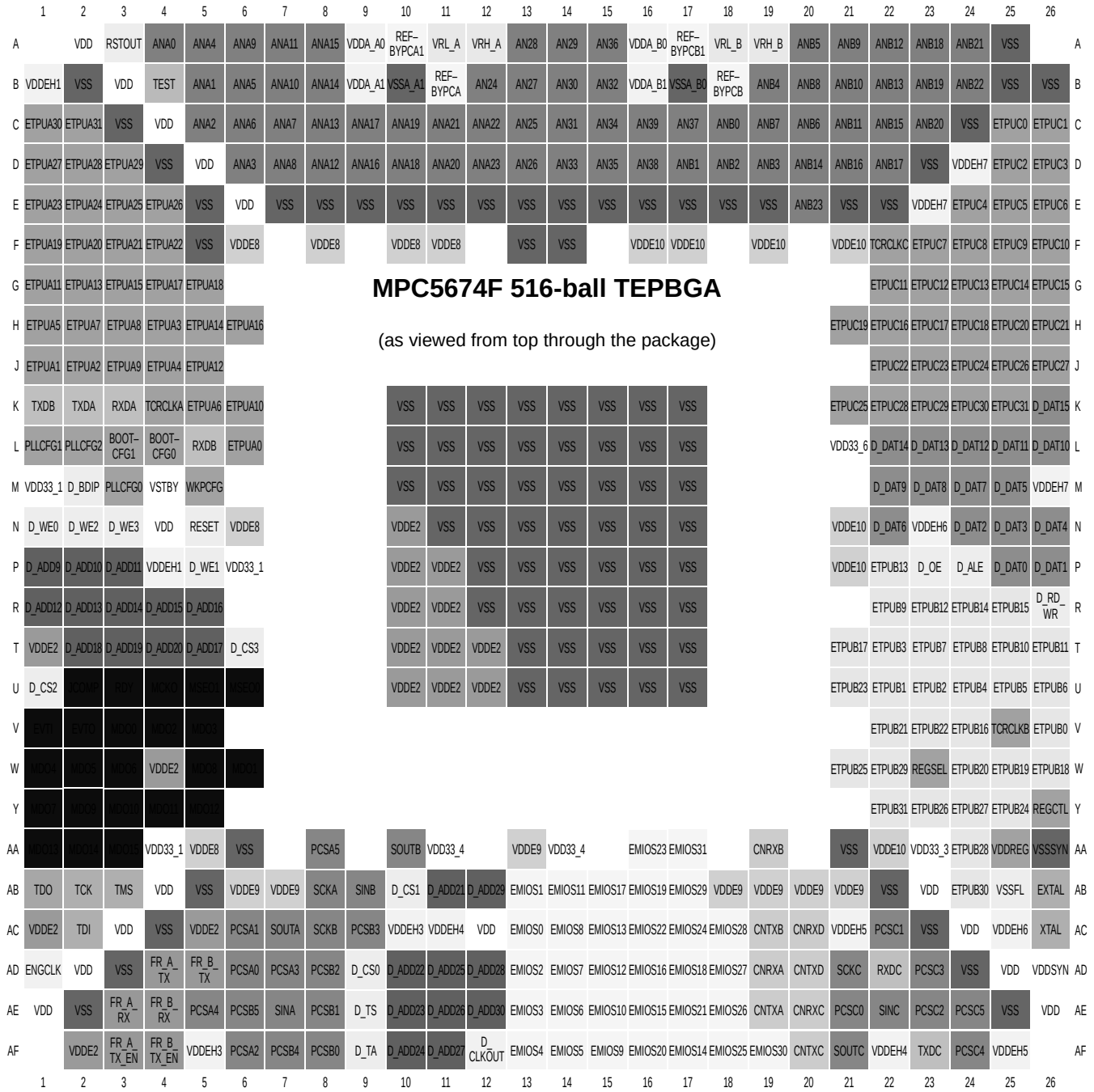

Figure 11. MPC5674F 516-ball TEPBGA (full diagram)

3.4 Signal Properties and Muxing

See Appendix A, Signal Properties and Muxing, for a listing and description of the pin functions and properties.

[1] Functional operating conditions are given in the DC electrical specifications. Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the listed maxima may affect device reliability or cause permanent damage to the device.

[2] 2.0 V for 10 hours cumulative time, 1.2V +10% for time remaining.

[3] 6.4 V for 10 hours cumulative time, 5.0V +10% for time remaining.

[4] Voltage overshoots during a high-to-low or low-to-high transition must not exceed 10 seconds per instance.

[5] 5.3 V for 10 hours cumulative time, 3.3V +10% for time remaining.

[6] MPC5674F has two analog power supply pins on the pinout: VDDA_A and VDDA_B.

[7] MPC5674F has two analog ground supply pins on the pinout: VSSA_A and VSSA_B.

[8] MPC5674F has two analog low reference voltage pins on the pinout: VRL_A and VRL_B.

[9] MPC5674F has two analog high reference voltage pins on the pinout: VRH_A and VRH_B.

[10] Total injection current for all pins must not exceed 25 mA at maximum operating voltage.

[11] Injection current of ±5 mA allowed for limited duration for analog (ADC) pads and digital 5 V pads. The maximum accumulated time at this current shall be 60 hours. This includes an assumption of a 5.25 V maximum analog or V_{DDEH} supply when under this stress condition.

[12] Total injection current for all analog input pins must not exceed 15 mA.

[13] Lifetime operation at these specification limits is not guaranteed.

[14] Solder profile per CDF-AEC-Q100.

[15] Moisture sensitivity per JEDEC test method A112.

4.2 Thermal Characteristics

Table 4. Thermal Characteristics, 416-pin TEPBGA Package[1]

Characteristic	Symbol	Value	Unit
Junction to Ambient [2,3] Natural Convection (Single layer board)	$R_{\theta JA}$	24	°C/W
Junction to Ambient [2,4] Natural Convection (Four layer board 2s2p)	$R_{\theta JA}$	18	°C/W
Junction to Ambient (@200 ft./min., Single layer board)	$R_{\theta JMA}$	19	°C/W
Junction to Ambient (@200 ft./min., Four layer board 2s2p)	$R_{\theta JMA}$	14	°C/W
Junction to Board [5]	$R_{\theta JB}$	9	°C/W
Junction to Case [6]	$R_{\theta JC}$	6	°C/W
Junction to Package Top [7] Natural Convection	Ψ_{JT}	2	°C/W

[1] Thermal characteristics are targets based on simulation that are subject to change per device characterization. This data is PRELIMINARY based on similar package used on other devices.

[2] Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.

[3] Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.

[4] Per JEDEC JESD51-6 with the board horizontal.

[5] Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.

[6] Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature.

[7] Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

4.7.2 LVDS Pad Specifications

LVDS pads are implemented to support the MSC (Microsecond Channel) protocol, which is an enhanced feature of the DSPI module.

Table 16. DSPI LVDS pad specification

#	Characteristic	Symbol	Condition	Min. Value	Typ. Value	Max. Value	Unit
Data Rate							
1	Data Frequency	$f_{LVDSCLK}$	—	—	50	—	MHz
Driver Specs							
2	Differential output voltage	V_{OD}	SRC=0b00 or 0b11	150	—	400	mV
			SRC=0b01	90	—	320	
			SRC=0b10	160	—	480	
3	Common mode voltage (LVDS), VOS	V_{OS}	—	1.06	1.2	1.39	V
4	Rise/Fall time	T_R/T_F	—	—	2	—	ns
5	Propagation delay (Low to High)	T_{PLH}	—	—	4	—	ns
6	Propagation delay (High to Low)	T_{PHL}	—	—	4	—	ns
7	Delay (H/L), sync Mode	t_{PDSYNC}	—	—	4	—	ns
8	Delay, Z to Normal (High/Low)	T_{DZ}	—	—	500	—	ns
9	Diff Skew ltphla-tplhbl or ltplhb-tphlal	T_{SKEW}	—	—	—	0.5	ns
Termination							
10	Trans. Line (differential Zo)	—	—	95	100	105	ohms
11	Temperature	—	—	–40	—	150	°C

4.8 Oscillator and FMPLL Electrical Characteristics

Table 17. FMPLL Electrical Specifications[1]

(V_{DDSYN} = 3.0 V to 3.6 V, V_{SS} = V_{SSSYN} = 0 V, T_A = T_L to T_H)

Spec	Characteristic	Symbol	Min	Max	Unit
1	PLL Reference Frequency Range[2] (Normal Mode) Crystal Reference (PLLCFG2 = 0b0) Crystal Reference (PLLCFG2 = 0b1) External Reference (PLLCFG2 = 0b0) External Reference (PLLCFG2 = 0b1)	 $f_{ref\_crystal}$ $f_{ref\_crystal}$ f_{ref_ext} f_{ref_ext}	 8 16 8 16	 20 40[3] 20 40	MHz
2	Loss of Reference Frequency[4]	f_{LOR}	100	1000	kHz
3	Self Clocked Mode Frequency[5]	f_{SCM}	4	16	MHz
4	PLL Lock Time[6]	t_{LPLL}	—	< 400	µs

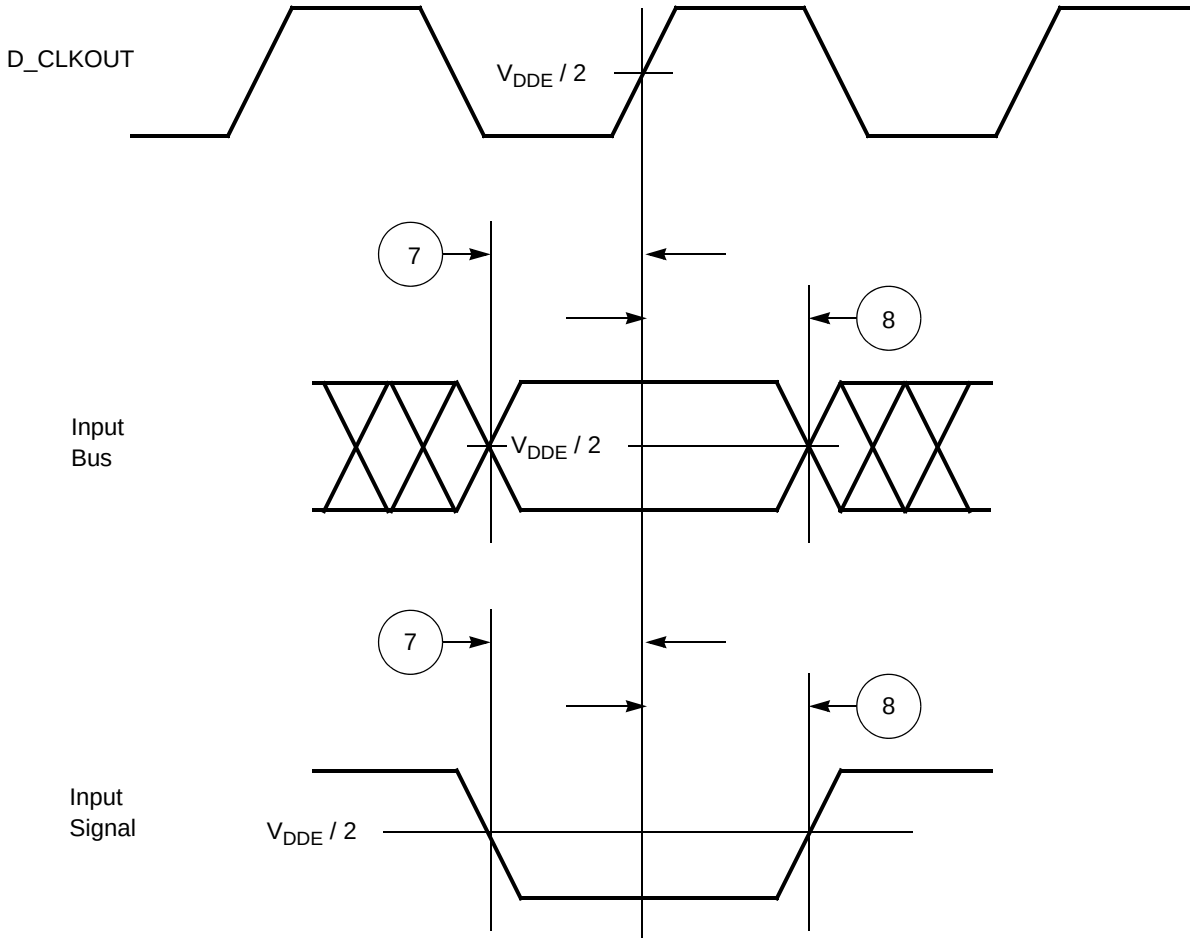

Figure 29. Synchronous Input Timing

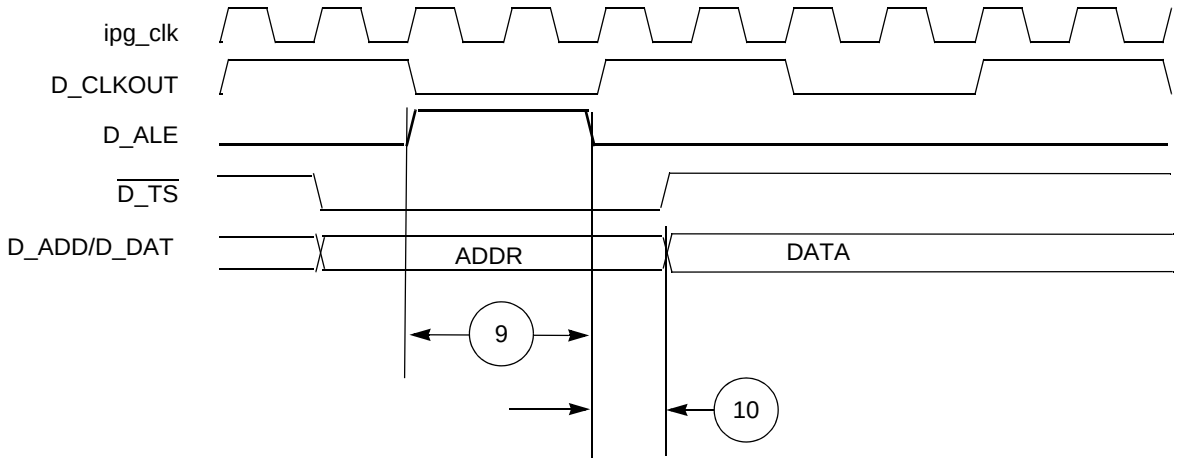

Figure 30. ALE Signal Timing

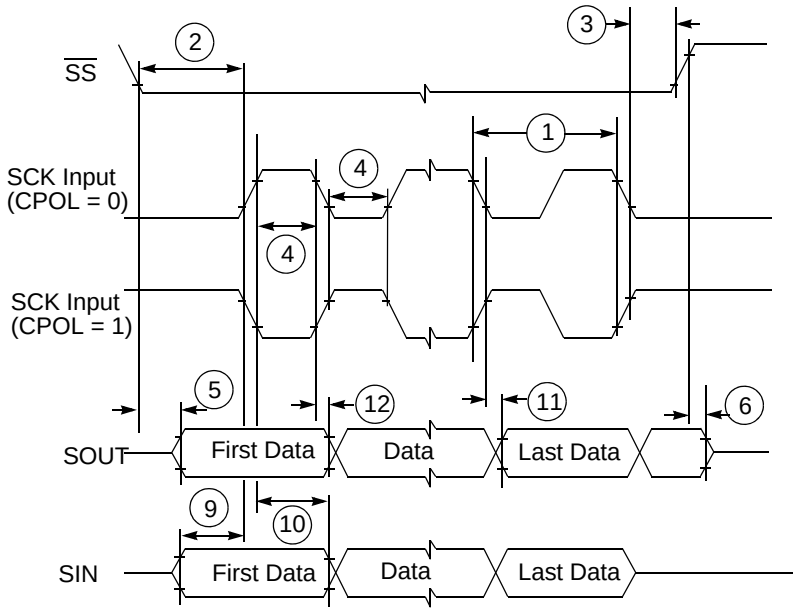

Figure 36. DSPI Classic SPI Timing — Slave, CPHA = 0

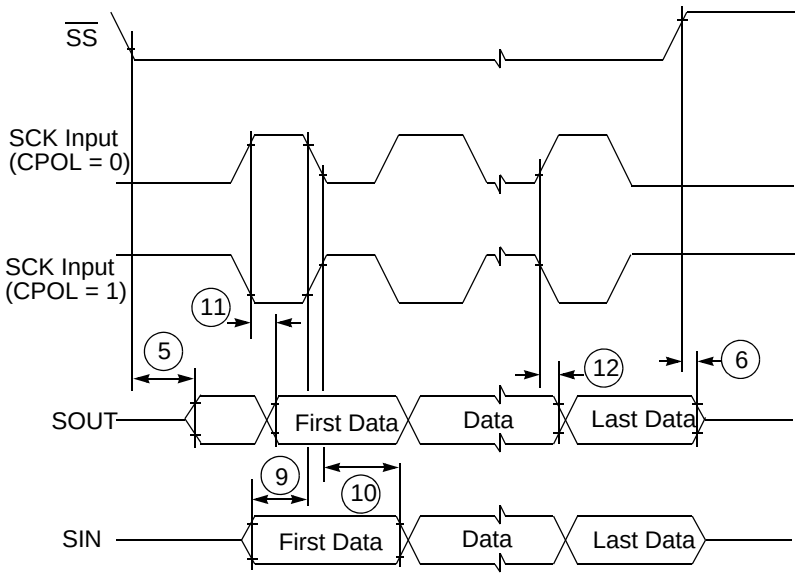

Figure 37. DSPI Classic SPI Timing — Slave, CPHA = 1

Figure 44. 324 TEPBGA Package (2 of 2)

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
143	ETPUA29_PCSC2_ GPIO143	P	ETPUA29	eTPU A channel	I/O	MH	V_{DDEH1}	—/WKPCFG	—/WKPCFG	—	D3	D3
		A1	PCSC2	DSPI C peripheral chip select	O							
		A2	—	—	—							
		G	GPIO143	GPIO	I/O							
144	ETPUA30_PCSC3_ GPIO144	P	ETPUA30	eTPU A channel	I/O	MH	V_{DDEH1}	—/WKPCFG	—/WKPCFG	E4	C1	C1
		A1	PCSC3	DSPI C peripheral chip select	O							
		A2	—	—	—							
		G	GPIO144	GPIO	I/O							
145	ETPUA31_PCSC4_ GPIO145	P	ETPUA31	eTPU A channel	I/O	MH	V_{DDEH1}	—/WKPCFG	—/WKPCFG	D3	C2	C2
		A1	PCSC4	DSPI C peripheral chip select	O							
		A2	—	—	—							
		G	GPIO145	GPIO	I/O							
eTPU_B												
146	TCRCLKB_IRQ6_ GPIO146	P	TCRCLKB	eTPU B TCR clock	I	MH	V_{DDEH6}	—/Up	—/Up	P19	T23	V25
		A1	IRQ6	External interrupt request	I							
		A2	—	—	—							
		G	GPIO146	GPIO	I/O							
147	ETPUB0_ETPUB16_ GPIO147	P	ETPUB0	eTPU B channel	I/O	MH	V_{DDEH6}	—/WKPCFG	—/WKPCFG	N19	T24	V26
		A1	ETPUB16	eTPU B channel (output only)	O							
		A2	—	—	—							
		G	GPIO147	GPIO	I/O							
148	ETPUB1_ETPUB17_ GPIO148	P	ETPUB1	eTPU B channel	I/O	MH	V_{DDEH6}	—/WKPCFG	—/WKPCFG	R19	T25	U22
		A1	ETPUB17	eTPU B channel (output only)	O							
		A2	—	—	—							
		G	GPIO148	GPIO	I/O							

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
182	EMIOS3_ETPUA3_ GPIO182	P	EMIOS3	eMIOS channel	I/O	MH	V_{DDEH4}	—/WKPCFG	—/WKPCFG	AA10	AE11	AE13
		A1	ETPUA3	eTPU A channel	O							
		A2	—	—	—							
		G	GPIO182	GPIO	I/O							
183	EMIOS4_ETPUA4_ GPIO183	P	EMIOS4	eMIOS channel	I/O	MH	V_{DDEH4}	—/WKPCFG	—/WKPCFG	AB10	AF11	AF13
		A1	ETPUA4	eTPU A channel	O							
		A2	—	—	—							
		G	GPIO183	GPIO	I/O							
184	EMIOS5_ETPUA5_ GPIO184	P	EMIOS5	eMIOS channel	I/O	MH	V_{DDEH4}	—/WKPCFG	—/WKPCFG	Y11	AD12	AF14
		A1	ETPUA5	eTPU A channel	O							
		A2	—	—	—							
		G	GPIO184	GPIO	I/O							
185	EMIOS6_ETPUA6_ GPIO185	P	EMIOS6	eMIOS channel	I/O	MH	V_{DDEH4}	—/WKPCFG	—/WKPCFG	—	AE12	AE14
		A1	ETPUA6	eTPU A channel	O							
		A2	—	—	—							
		G	GPIO185	GPIO	I/O							
186	EMIOS7_ETPUA7_ GPIO186	P	EMIOS7	eMIOS channel	I/O	MH	V_{DDEH4}	—/WKPCFG	—/WKPCFG	AB11	AF12	AD14
		A1	ETPUA7	eTPU A channel	O							
		A2	—	—	—							
		G	GPIO186	GPIO	I/O							
187	EMIOS8_ETPUA8_ GPIO187	P	EMIOS8	eMIOS channel	I/O	MH	V_{DDEH4}	—/WKPCFG	—/WKPCFG	W10	AC13	AC14
		A1	ETPUA8	eTPU A channel	O							
		A2	—	—	—							
		G	GPIO187	GPIO	I/O							

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
—	ANB9	P	ANB9	eQADC B analog input	I	AE	V_{DDA_B0}	ANB9	ANB9	C14	D20	A21
—	ANB10	P	ANB10	eQADC B analog input	I	AE	V_{DDA_B0}	ANB10	ANB10	C13	B21	B21
—	ANB11	P	ANB11	eQADC B analog input	I	AE	V_{DDA_B0}	ANB11	ANB11	C15	A21	C21
—	ANB12	P	ANB12	eQADC B analog input	I	AE	V_{DDA_B0}	ANB12	ANB12	C16	C21	A22
—	ANB13	P	ANB13	eQADC B analog input	I	AE	V_{DDA_B0}	ANB13	ANB13	D14	D21	B22
—	ANB14	P	ANB14	eQADC B analog input	I	AE	V_{DDA_B0}	ANB14	ANB14	C17	A22	D20
—	ANB15	P	ANB15	eQADC B analog input	I	AE	V_{DDA_B0}	ANB15	ANB15	D15	B22	C22
—	ANB16	P	ANB16	eQADC B analog input	I	AE	V_{DDA_B0}	ANB16	ANB16	C18	C22	D21
—	ANB17	P	ANB17	eQADC B analog input	I	AE	V_{DDA_B0}	ANB17	ANB17	D16	A23	D22
—	ANB18	P	ANB18	eQADC B analog input	I	AE	V_{DDA_B0}	ANB18	ANB18	D17	B23	A23
—	ANB19	P	ANB19	eQADC B analog input	I	AE	V_{DDA_B0}	ANB19	ANB19	B19	C23	B23
—	ANB20	P	ANB20	eQADC B analog input	I	AE	V_{DDA_B0}	ANB20	ANB20	C19	D22	C23
—	ANB21	P	ANB21	eQADC B analog input	I	AE	V_{DDA_B0}	ANB21	ANB21	D18	A24	A24
—	ANB22	P	ANB22	eQADC B analog input	I	AE	V_{DDA_B0}	ANB22	ANB22	A21	B24	B24
—	ANB23	P	ANB23	eQADC B analog input	I	AE	V_{DDA_B0}	ANB23	ANB23	B20	A25	E20
—	VRH_A	P	VRH_A	ADC A Voltage reference high	I	VDDINT	V_{RH_A}	VRH_A	VRH_A	A10	A12	A12
—	VRL_A	P	VRL_A	ADC A Voltage reference low	I	VSSINT	V_{RL_A}	VRL_A	VRL_A	A11	A11	A11
—	VRH_B	P	VRH_B	ADC B Voltage reference high	I	VDDINT	V_{RH_B}	VRH_B	VRH_B	A16	A19	A19
—	VRL_B	P	VRL_B	ADC B Voltage reference low	I	VSSINT	V_{RL_B}	VRL_B	VRL_B	A15	A18	A18
—	REFBYPCB	P	REFBYPCB	ADC B Reference bypass capacitor	I	AE	V_{DDA_B0}	REFBYPCB	REFBYPCB	B12	B18	B18
—	REFBYPCA	P	REFBYPCA	ADC A Reference bypass capacitor	I	AE	V_{DDA_A1}	REFBYPCA	REFBYPCA	B11	B11	B11
—	VDDA_A0	P	VDDA_A	Internal logic supply input	I	VDDE	V_{DDA_A0}	VDDA_A0	VDDA_A0	A9	A9	A9
—	VDDA_A1	P	VDDA_A	Internal logic supply input	I	VDDE	V_{DDA_A1}	VDDA_A1	VDDA_A1	B9	B9	B9
—	REFBYPCA1	P	REFBYPCA1	ADC A Reference bypass capacitor	I	AE	V_{DDA_A1}	REFBYPCA1	REFBYPCA1	A12	A10	A10
—	VSSA_A1	P	VSSA_A	Ground	I	VSSE	V_{SSA_A1}	VSSA_A1	VSSA_A1	B10	B10	B10
—	VDDA_B0	P	VDDA_B	Internal logic supply input	I	VDDE	V_{DDA_B0}	VDDA_B0	VDDA_B0	A13	A16	A16
—	VDDA_B1	P	VDDA_B	Internal logic supply input	I	VDDE	V_{DDA_B1}	VDDA_B1	VDDA_B1	B13	B16	B16

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
238	PCSC0_SOUT_C_LVDSM_ GPIO238	P	PCSC0	DSPI C peripheral chip select	I/O	MH+ LVDS	V_{DDEH4}	—/Up	—/Up	AB19	AE21	AE21
		A1	SOUT_C_LVDSM	LVDS– downstream signal negative output data	O							
		A2	—	—	—							
		G	GPIO238	GPIO	I/O							
239	PCSC1_ GPIO239	P	PCSC1	DSPI C peripheral chip select	O	MH	V_{DDEH4}	—/Up	—/Up	—	AC22	AC22
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO239	GPIO	I/O							
240	PCSC2_GPIO240	P	PCSC2	DSPI C peripheral chip select	O	MH	V_{DDEH5}	—/Up	—/Up	—	AE23	AE23
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO240	GPIO	I/O							
241	PCSC3_GPIO241	P	PCSC3	DSPI C peripheral chip select	O	MH	V_{DDEH5}	—/Up	—/Up	—	AD23	AD23
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO241	GPIO	I/O							
242	PCSC4_GPIO242	P	PCSC4	DSPI C peripheral chip select	O	MH	V_{DDEH5}	—/Up	—/Up	—	AF24	AF24
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO242	GPIO	I/O							
243	PCSC5_GPIO243	P	PCSC5	DSPI C peripheral chip select	O	MH	V_{DDEH5}	—/Up	—/Up	—	AE24	AE24
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO243	GPIO	I/O							

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
278	D_ADD_DAT0_ GPIO278	P	D_ADD_DAT0	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	P25
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO278	GPIO	I/O							
279	D_ADD_DAT1_ GPIO279	P	D_ADD_DAT1	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	P26
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO279	GPIO	I/O							
280	D_ADD_DAT2_ GPIO280	P	D_ADD_DAT2	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	N24
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO280	GPIO	I/O							
281	D_ADD_DAT3_ GPIO281	P	D_ADD_DAT3	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	N25
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO281	GPIO	I/O							
282	D_ADD_DAT4_ GPIO282	P	D_ADD_DAT4	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	N26
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO282	GPIO	I/O							

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
283	D_ADD_DAT5_ GPIO283	P	D_ADD_DAT5	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	M25
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO283	GPIO	I/O							
284	D_ADD_DAT6_ GPIO284	P	D_ADD_DAT6	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	N22
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO284	GPIO	I/O							
285	D_ADD_DAT7_ GPIO285	P	D_ADD_DAT7	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	M24
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO285	GPIO	I/O							
286	D_ADD_DAT8_ GPIO286	P	D_ADD_DAT8	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	M23
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO286	GPIO	I/O							
287	D_ADD_DAT9_ GPIO287	P	D_ADD_DAT9	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	M22
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO287	GPIO	I/O							

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
288	D_ADD_DAT10_ GPIO288	P	D_ADD_DAT10	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	L26
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO288	GPIO	I/O							
289	D_ADD_DAT11_ GPIO289	P	D_ADD_DAT11	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	L25
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO289	GPIO	I/O							
290	D_ADD_DAT12_ GPIO290	P	D_ADD_DAT12	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	L24
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO290	GPIO	I/O							
291	D_ADD_DAT13 _GPIO291	P	D_ADD_DAT13	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	L23
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO291	GPIO	I/O							
292	D_ADD_DAT14_GPIO292	P	D_ADD_DAT14	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	L22
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO292	GPIO	I/O							

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
293	D_ADD_DAT15_GPIO293	P	D_ADD_DAT15	EBI data only in non-mux mode. Address and data in mux mode.	I/O	F	V_{DDE10}	—/Up	—/Up	—	—	K26
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO293	GPIO	I/O							
294	D_RD_WR_GPIO294	P	D_RD_WR	EBI read/write	O	F	V_{DDE10}	—/Up	—/Up	—	—	R26
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO294	GPIO	I/O							
295	D_WE0_GPIO295	P	D_WE0	EBI write enable	O	F	V_{DDE8}	—/Up	—/Up	—	—	N1
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO295	GPIO	I/O							
296	D_WE1_GPIO296	P	D_WE1	EBI write enable	O	F	V_{DDE8}	—/Up	—/Up	—	—	P5
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO296	GPIO	I/O							
297	D_OE_GPIO297	P	D_OE	EBI output enable	O	F	V_{DDE10}	—/Up	—/Up	—	—	P23
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO297	GPIO	I/O							
298	D_TS_GPIO298	P	D_TS	EBI transfer start	O	F	V_{DDE9}	—/Up	—/Up	—	—	AE9
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO298	GPIO	I/O							

Table 42. Signal Properties and Muxing Summary (continued)

GPIO/PCR[1]	Signal Name[2]	P/A/G[3]	Function[4]	Function Summary	Direction	Pad Type[5]	Voltage[6]	State during RESET[7]	State after RESET[8]	Package Location		
										324	416	516
299	D_ALE_GPIO299	P	D_ALE	EBI Address Latch Enable	O	F	V_{DDE10}	—/Up	—/Up	—	—	P24
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO299	GPIO	I/O							
300	D_TA_GPIO300	P	D_TA	EBI transfer acknowledge	I/O	F	V_{DDE9}	—/Up	—/Up	—	—	AF9
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO300	GPIO	I/O							
301	D_CS1_GPIO301	P	D_CS1	EBI chip select	O	F	V_{DDE9}	—/Up	—/Up	—	—	AB10
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO301	GPIO	I/O							
302	D_BDIP_GPIO302	P	D_BDIP	EBI burst data in progress	O	F	V_{DDE8}	—/Up	—/Up	—	—	M2
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO302	GPIO	I/O							
303	D_WE2_GPIO303	P	D_WE2	EBI write enable	O	F	V_{DDE8}	—/Up	—/Up	—	—	N2
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO303	GPIO	I/O							
304	D_WE3_GPIO304	P	D_WE3	EBI write enable	O	F	V_{DDE8}	—/Up	—/Up	—	—	N3
		A1	—	—	—							
		A2	—	—	—							
		G	GPIO304	GPIO	I/O							

Table 43 lists the pin locations of the power and ground signals on the 324 TEPBGA package.

Table 43. 324-pin Power Supply Locations

VDD

A2	B3	C4	D5	K3	V19	W5	W9	W20	Y4	Y21	AA3	AA22	AB2

VDD33

W21	V4

VDDE2

AB4	M9	N1	N10	N9	P10	P9	T4	W6	V2

VDDEH1

B1	L4

VDDEH4

AB20	W8

VDDEH6

N20	T21

VDDEH7

C22	H19	L22

VSS

A1	A22	AA2	AA21	AB1	AB22	B2	B21	C20	C3	D19	D4	J10	J11	J12	J13	J14	J9
K10	K11	K12	K13	K14	K9	L10	L11	L12	L13	L14	L9	M10	M11	M12	M13	M14	N11
N12	N13	N14	P11	P12	P13	P14	W19	W4	Y20	Y3							

Table 46. Revision History (continued)

Revision (Date)	Description of changes
8 (Jun-2011)	Removed spec 3 from Table 27 “PFCPR1 Settings vs Frequency of Operation” Updated spec 2a (Untrimmed VRC 1.2V) in Table 11 “PMC Electrical Specifications“ to a max value of VDD12OUT + 17%. Updated item 26 (Operating Current VDDA Supply) in table 14 “Electrical Specifications” from 30 mA to 40 mA. Updated Note 11 for Table 14 (Electrical Specifications) to read IOH_F = {16,32,47,77} mA and IOL_F = {24,48,71,115} mA for {00,01,10,11} drive mode with VDDE = 3.0 V. Updated ID 9 in Table 11 (PMC Electrical Specifications) to V_{REG} = 4.5 V, max DC output current with a max of 80 mA V_{REG} = 4.25 V, max DC output current, crank condition with a max of 40 mA Updated Table 17 (DSPI LVDS Pad Specification) with the following: • Spec 1 typical value updated from 40 MHz to 50 MHz • Spec 2 added SRC conditions and associated values: – SRC=0b00 or SRC=0b11 Min 150 mV Max 400 mV – SRC=0b01 Min 90 mV Max 320 mV – SRC=0b10 Min 160 mV Max 480 mV • Spec 3 - Min value from 1.075 V to 1.06 V - Max value from 1.325 V to 1.39 V • Added Spec 5, 6 and 7
	Updated table 17 "DSPI LVDS pad specification" to include Temperature with a min value of -40 C and max of 150 C Updated Spec 5 of Table 18, "FMPLL Electrical Specifications" to < 400 us as the Max vaule. Added the sentence "Violating the VCO min/max range may prevent the system from exiting reset." to the end of Footnote 16 of Table 18, "FMPLL Electrical Specifications" Updated Spec 1 of Table 18, "FMPLL Electrical Specifications", Crystal Reference (PLLCFG2 = 0b1) minimum value from 40 MHz to 16 MHz. Updated Spec 1 of Table 18, "FMPLL Electrical Specifications", External Reference (PLLCFG2 = 0b1) minimum value from 40 MHz to 16 MHz. Removed Note 9, 'Duty cycle can be 20–80% when PLL is used with a pre-divider greater than 1', from Table 18, "FMPLL Electrical Specifications". Updated ID 16 in Table 11, “PMC Electrical Specifications”, SMPS regulator clock frequency (after reset) 2.4MHz Max
	Updated Table 16 “Flash EEPROM Module Life”, spec 3, ‘Blocks with 10,001–100,000 P/E cycles’ to 5 Years. Added Typ column to Table 25, “Flash Program and Erase Specifications”

Table 46. Revision History (continued)

Revision (Date)	Description of changes
	Updated Table 3, “Absolute Maximum Ratings” with the following: - Spec 1, ‘1.2 V Core Supply Voltage’, to a Max of 2.0 V - Spec 3, ‘Clock Synthesizer Voltage’, to a Max of 5.3 V - Spec 4, ‘I/O Supply Voltage’ to a Max of 5.3 V - Spec 5, ‘Analog Supply Voltage’ to a Max of 5.3 V - Note 2 to read, “2.0 V for 10 hours cumulative time, 1.32 V +10% for time remaining.“ - Note 3, “... 5.0 V + 10% ...” to “... 5.25 V + 10 % ...” - Note 5, “... 3.3 V + 10% ...” to “... 3.60 V + 10 % ...” Updated Spec 2 (ESD for Charged Device Model (CDM)) of Table 9, “ESD Ratings”, to 500 V Updated Table 27, “PFCPR1 Settings vs. Frequency of Operation“, Spec 3, APC = RWSC column to 0b100. Updated Spec 26, “Operating Current 5.0 V Supplies @ f_{sys} = 264 MHz“ for I_{DDA} to 50 mA, in Table 14, “DC electrical specifications”.